

UTC UNISONIC TECHNOLOGIES CO., LTD

FR104G **DIODE**

FAST RECOVERY GLASS PASSIVATED RECTIFIER

DESCRIPTION

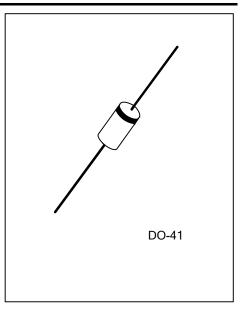
The UTC FR104G is a fast recovery glass passivated silicon rectifier, it uses UTC's advanced technology to provide customers with high forward surge current and low reverse leakage, etc.

FEATURES

- * Low reverse leakage
- * High forward surge current capability

SYMBOL

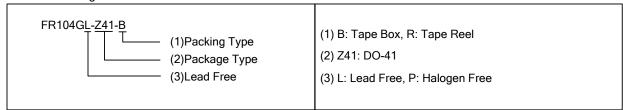




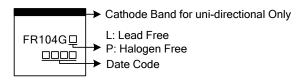
ORDERING INFORMATION

Ordering Number		Doolsono	Pin Assignment		Deaking	
Lead Free	Halogen Free	Package	1	2	Packing	
FR104GL-Z41-B	FR104GP-Z41-B	DO-41	K	Α	Tape Box	
FR104GL-Z41-R	FR104GP-Z41-R	DO-41	K	Α	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



MARKING



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■ ABSOLUTE MAXIMUM RATINGS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
Working Peak Reverse Voltage	V_{RWM}	400	V
Repetitive Peak Reverse Voltage	V_{RRM}	400	V
Maximum RMS Reverse Voltage	V_{RMS}	280	V
DC Blocking Voltage	V_R	400	V
Average Rectified Output Current (T _A =105°C)	Io	1.0	Α
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	30	Α
Junction Temperature	T_J	-55~+150	°C
Storage Temperature	T _{STG}	-55~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient (Note 3)	θ_{JA}	50	°C/W

■ ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

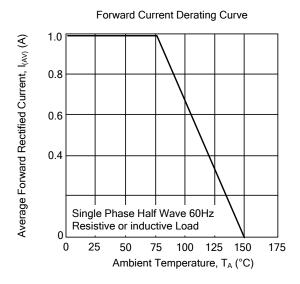
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Instantaneous Forward Voltage	V_{FM}	I _F =1.0A			1.3	V
DC Reverse Current at Rated DC Blocking		T _A =25°C			5.0	μΑ
Voltage	I _{RM}	T _A =100°C			50	μΑ
Reverse Recovery Time (Note 1)	t _{rr}				150	ns
Junction Capacitance (Note 2)	CJ			15.0		pF

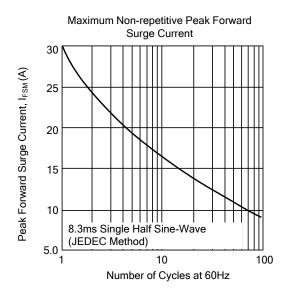
Notes: 1. Reverse recovery condition I_F=0.5A, I_R=1.0A, Irr=0.25A

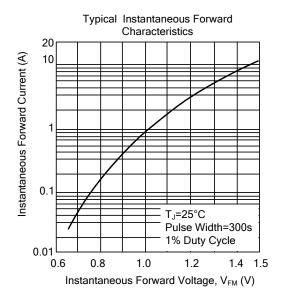
- 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
- 3. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted.

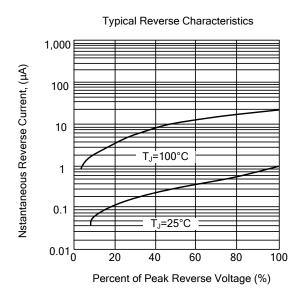
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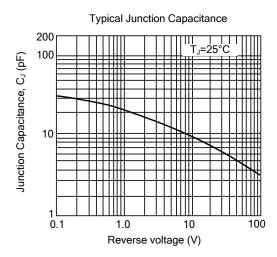
■ TYPICAL CHARACTERISTICS

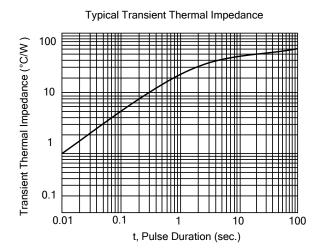












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